

Tribute to Prof. Larry Coldren



Connie Chang-Hasnain
EECS Dept.
UC Berkeley

UCSB
3/16/2018

VCSELs



After Microsoft
(Univ.Ulm)

Sensing



After Fuji Xerox

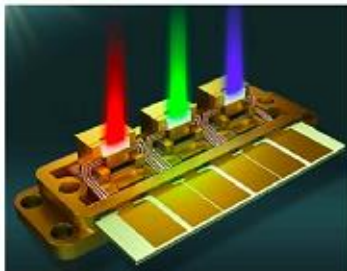
Printing



Datacom

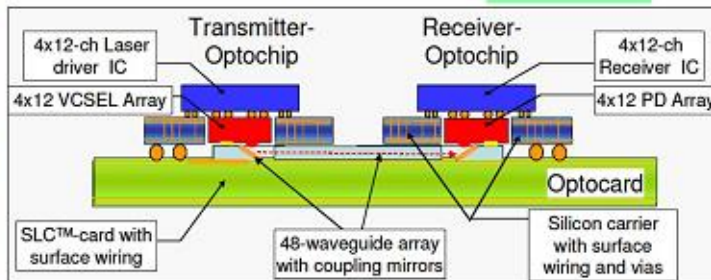
VCSEL Photonics

Display

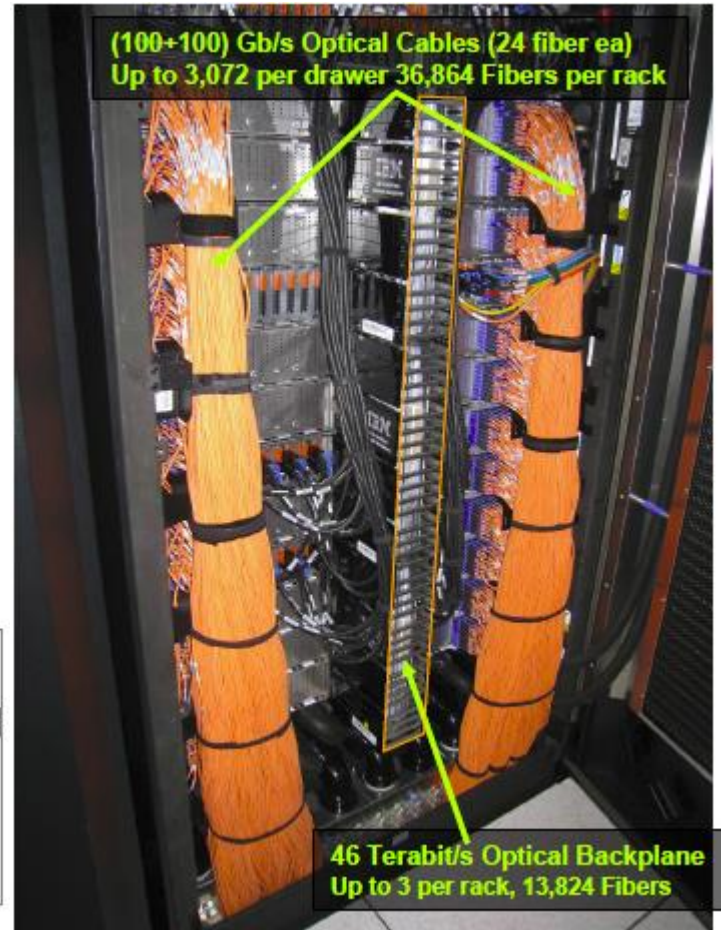


After Novalux

Interconnects



After IBM/Agilent

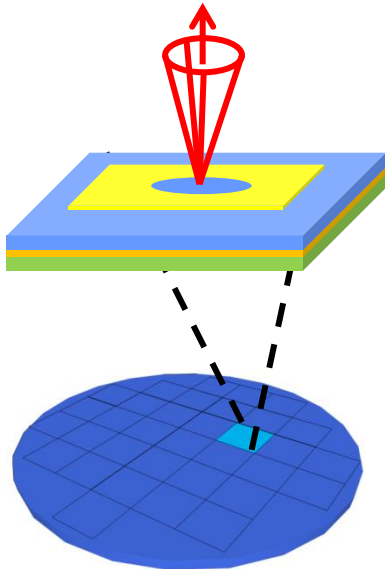


Kenichi Iga, *Proceedings of the IEEE* (2013).

Vertical-Cavity Surface-Emitting Laser (VCSEL)

Advantages

- Excellent fiber coupling
- Low power consumption
- Wafer-scale testing, Low-cost fabrication
- **Single longitudinal mode**
- **2D Array fabrication**

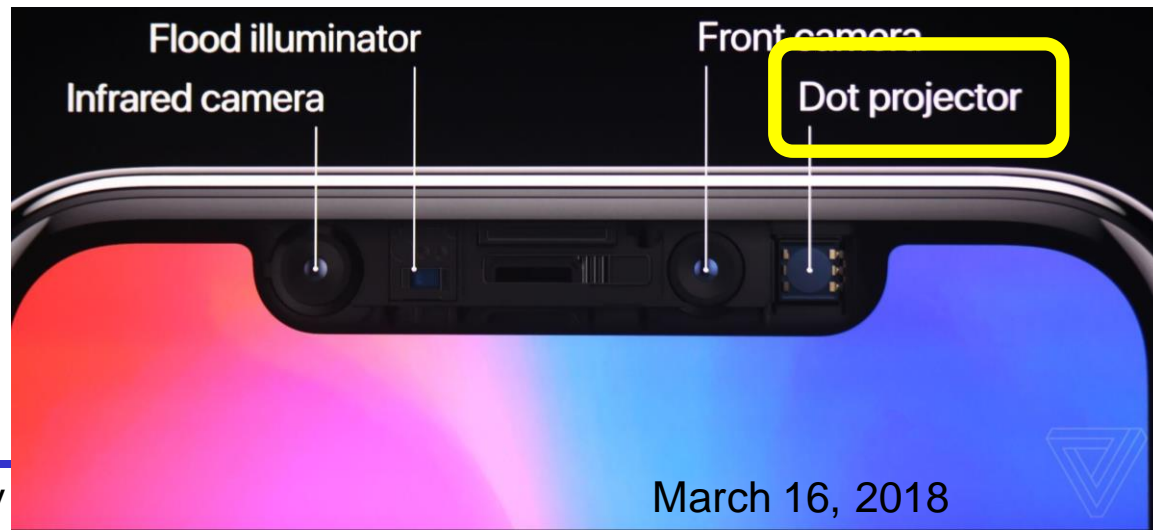


New Applications in 3D Sensing



**Optical
Coherent
Tomography**

3D sensing

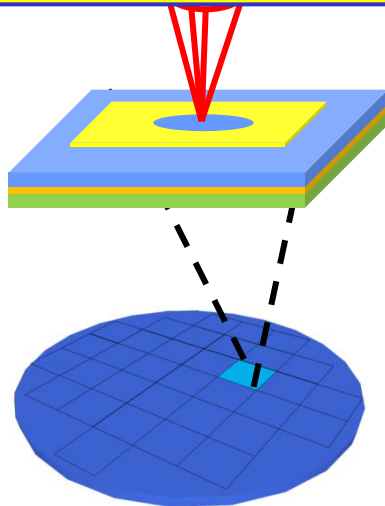


Vertical-Cavity Surface Emitting Laser (VCSEL)

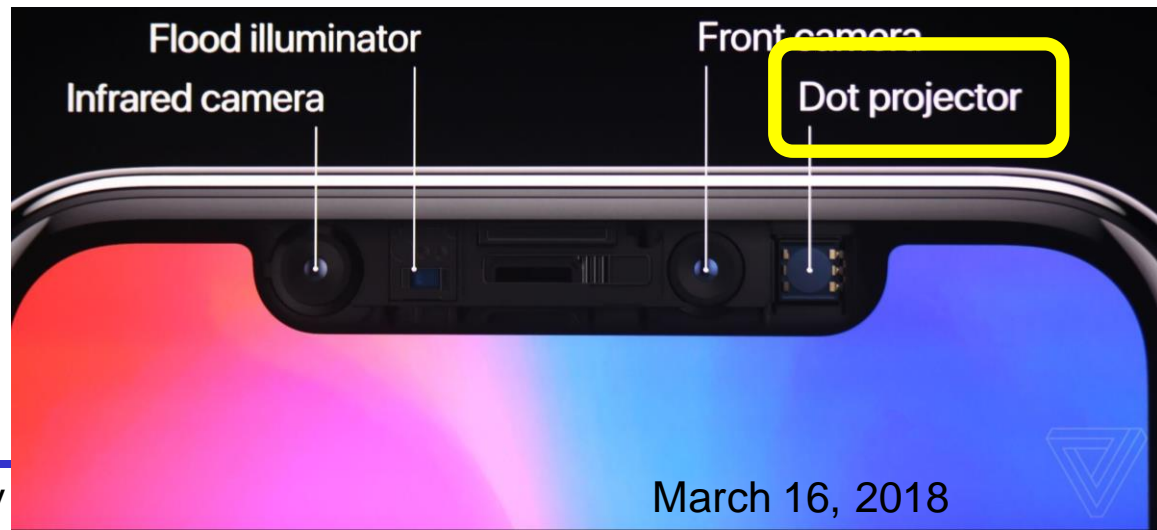
- **Advantages**

- Excellent fiber coupling

Rapidly growing to B\$/year market for 3D sensing in smart phones and facial recognition applications.



3D sensing



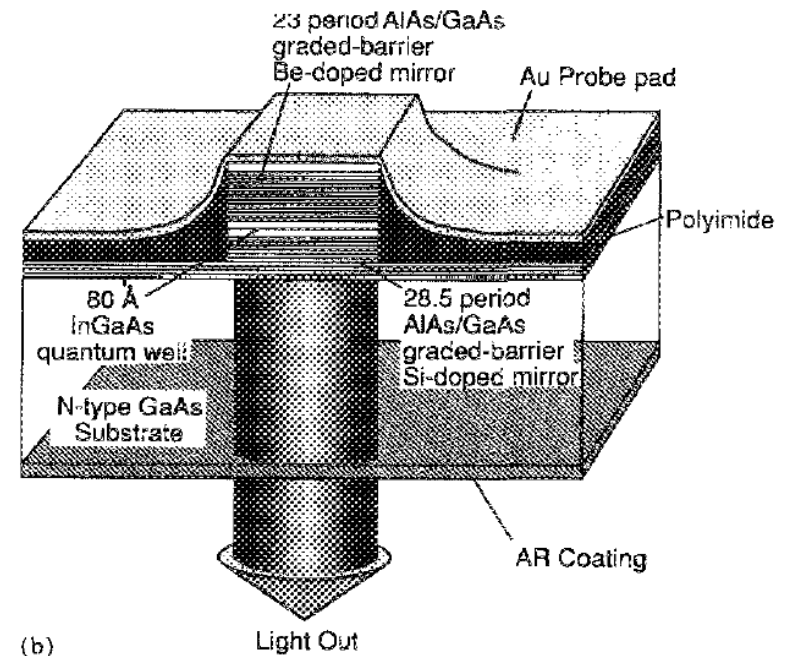
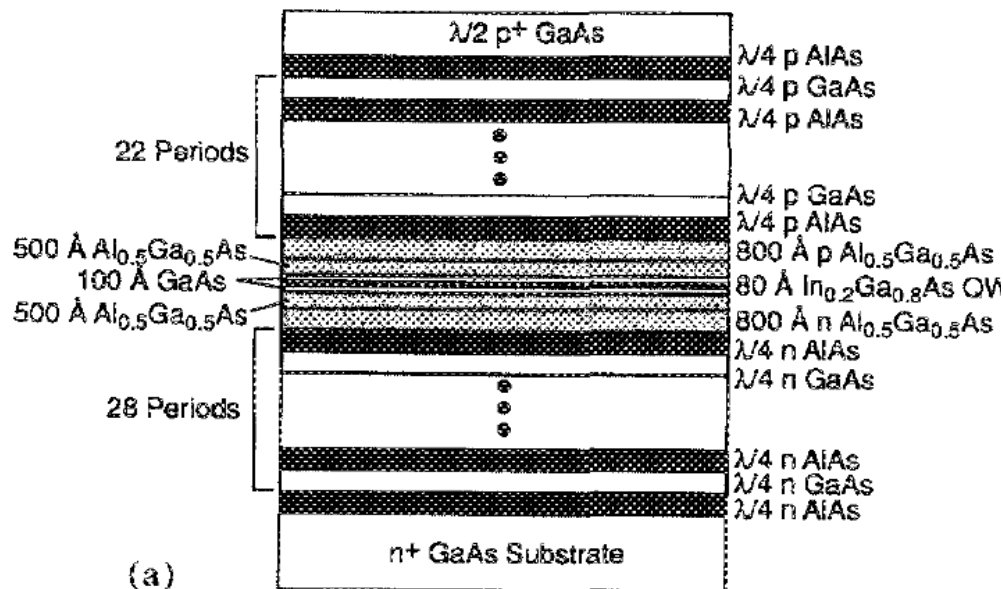
Submilliamp threshold vertical-cavity laser diodes

Randall S. Geels and Larry A. Coldren

Department of Electrical and Computer Engineering, University of California, Santa Barbara, California 93106

(Received 18 June 1990; accepted for publication 8 August 1990)

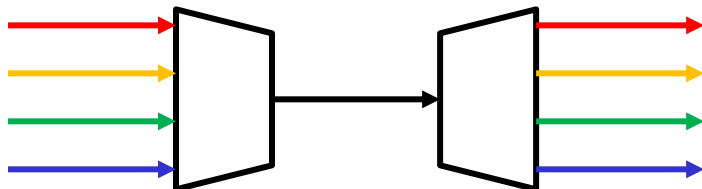
We report for the first time room-temperature, continuous-wave operation of individual vertical-cavity laser diodes with submilliampere threshold currents. A single quantum well active region emitting at 979 nm surrounded by GaAs/AlAs Bragg reflector mirrors was used. Threshold currents were as low as 0.7 mA. A record low linewidth-power product of 5 MHz mW and a linewidth as narrow as 85 MHz was measured. High yield and good uniformity were demonstrated.



Tunable VCSEL Applications

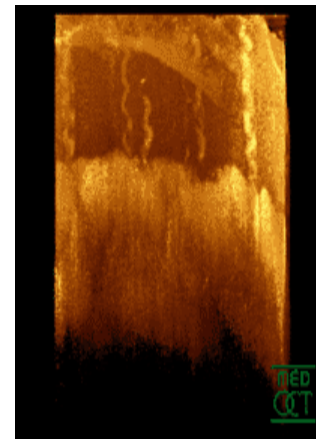
Optical Communications

- Wavelength Division Multiplexing (WDM)
- Dense WDM (DWDM)
 - O-band: 1260 nm-1360 nm
 - S-band: 1450 nm-1530 nm
 - C-band: 1530 nm-1565 nm
 - L-band: 1565 nm-1625 nm
- Shortwave WDM (SWDM4)
 - 850 nm - 940 nm
- Coarse WDM (CWDM)
 - 20 nm per channel



Optical Coherence Tomography

- Depth Resolution $\delta z = \frac{2 \ln 2}{\pi} \frac{\lambda^2}{\Delta \lambda}$
 - 50 nm+ for 10 μm resolution
 - 100 nm+ for 5 μm resolution
- Field of View \propto sweep rate
 - *In vivo* Optical Coherence Tomography



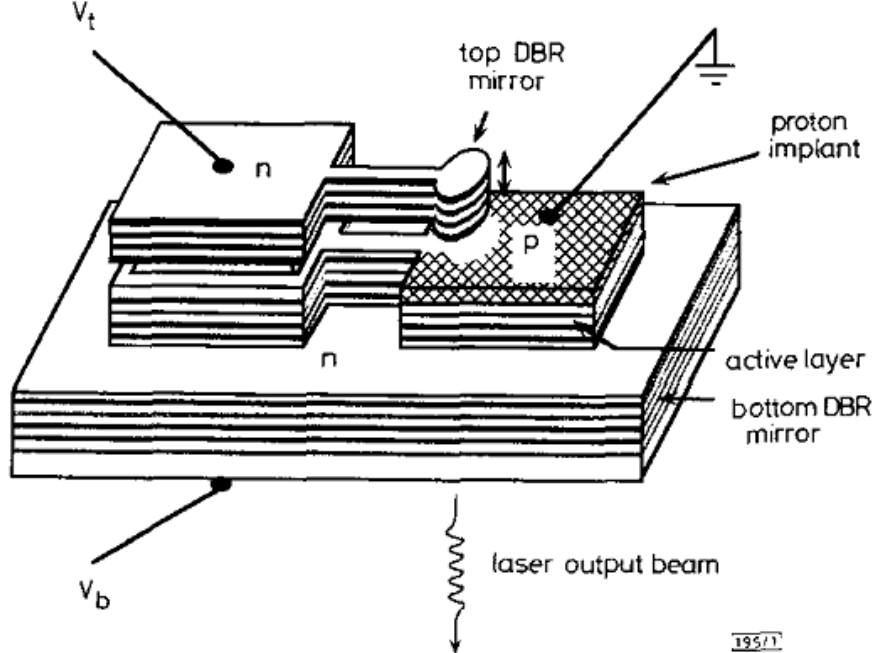
medOCT group, Center of biomedical Engineering and Physics, Medical University Vienna, Austria



Electrostatic Tuning of MEMS-VCSEL

First MEMS Tunable VCSEL

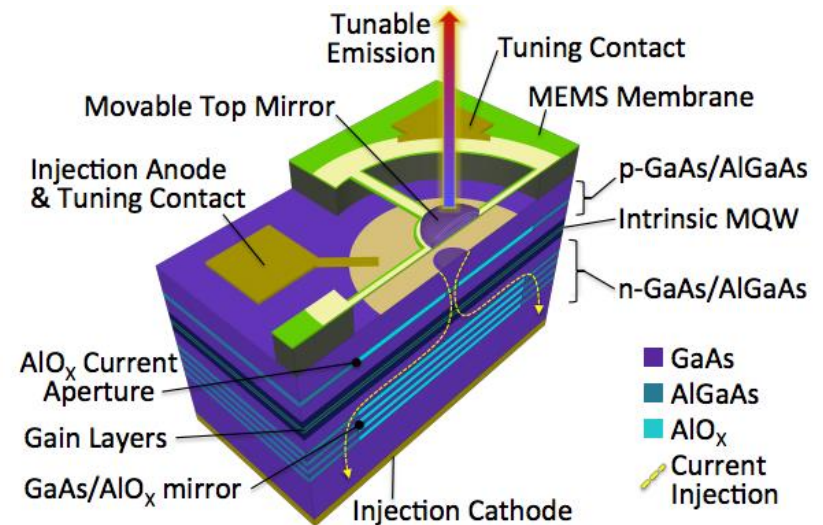
- 940-nm VCSEL; suspended cantilever GaAs/AlGaAs DBR
- Electrostatic tuning ~32 nm, 300 kHz



Chang-Hasnain group, LEOS Conference, post-deadline, 1994; M.S. Wu, *Electron. Lett.* 1995.

Praevium/Thorlabs

- Electrically pumped 1060 nm VCSEL with 63.8 nm sweep
 - $I_{th} \sim 0.5$ mA, $P_{out} \sim 0.4$ mW
 - 150 kHz sweep rate
- OCT applications



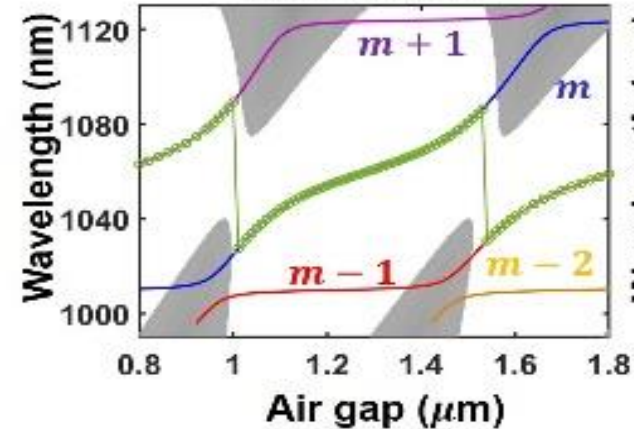
D. D. John, et. al, *J. of Lightwave Technol.* (2015).



New Design – Tale of Two Cavities

**Semiconductor
Cavity Dominant
(SCD)**

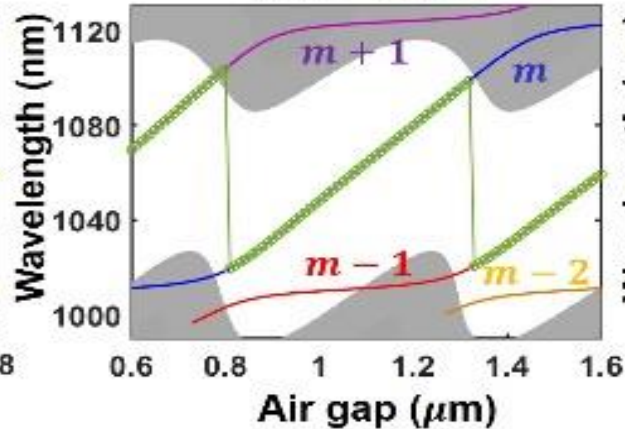
$\Delta\lambda = 59 \text{ nm}$



(a)

**Extended Cavity
(EC)**

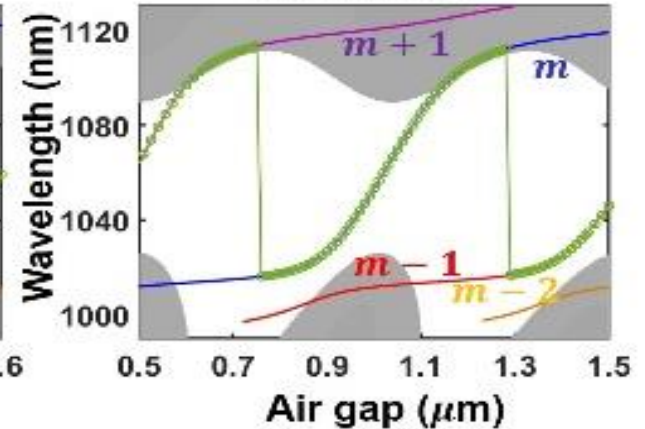
$\Delta\lambda = 79 \text{ nm}$



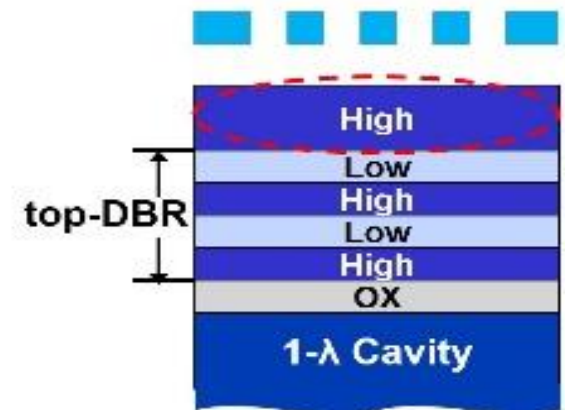
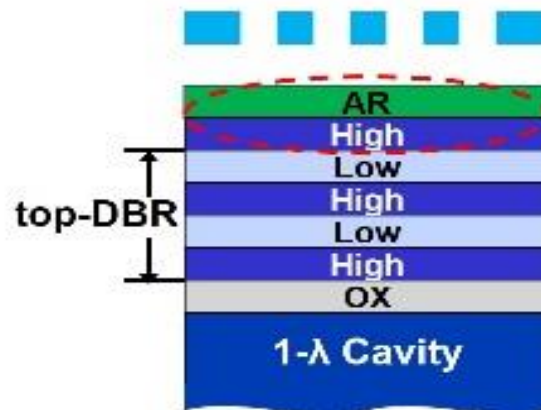
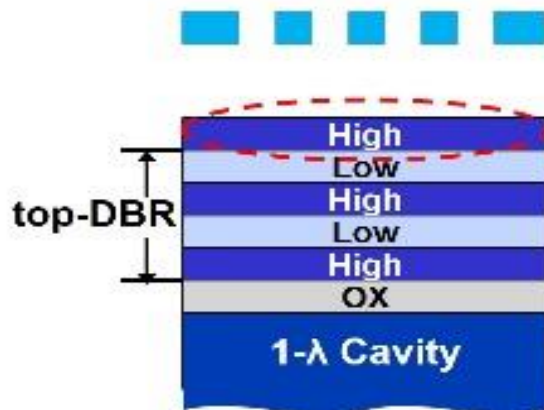
(b)

**Air Cavity
Dominant (ACD)**

$\Delta\lambda = 96 \text{ nm}$

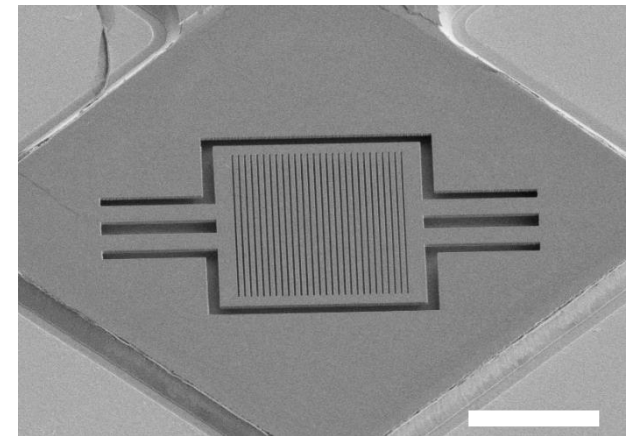
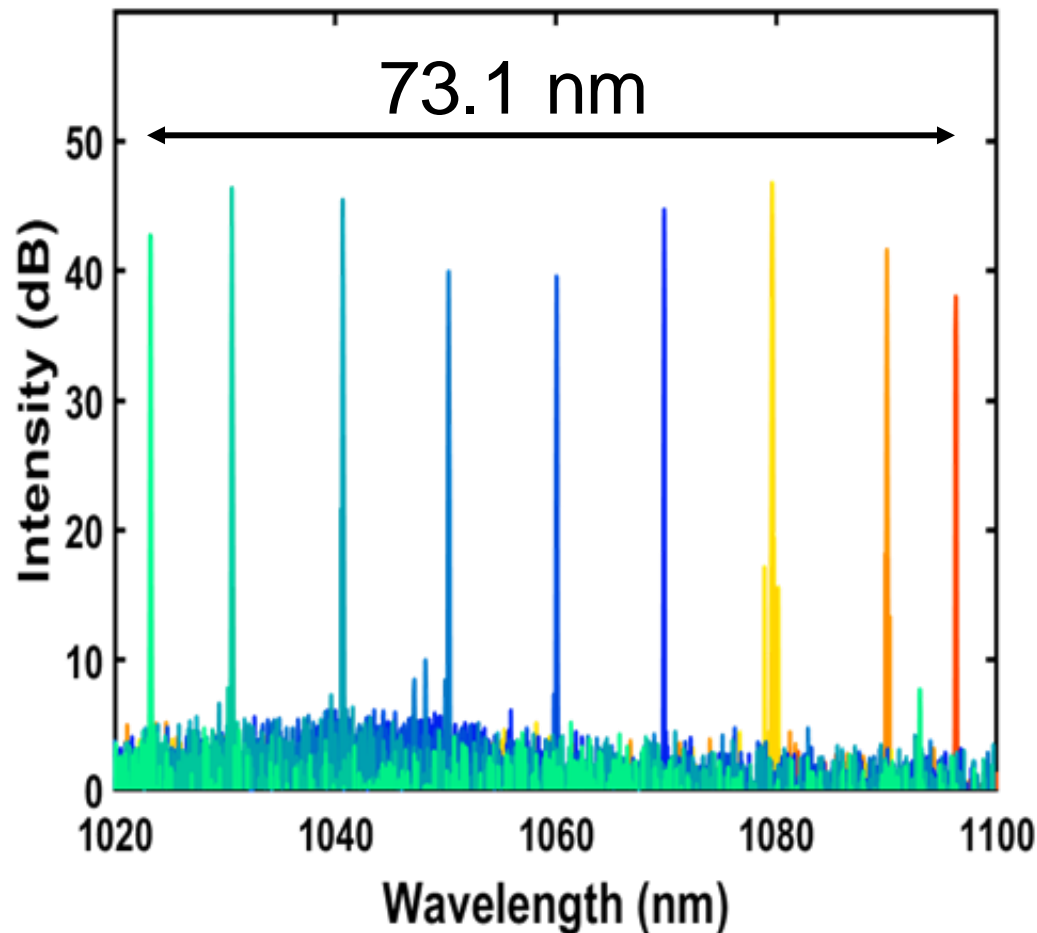


(c)



Record Tuning Ratio @ 1060 nm

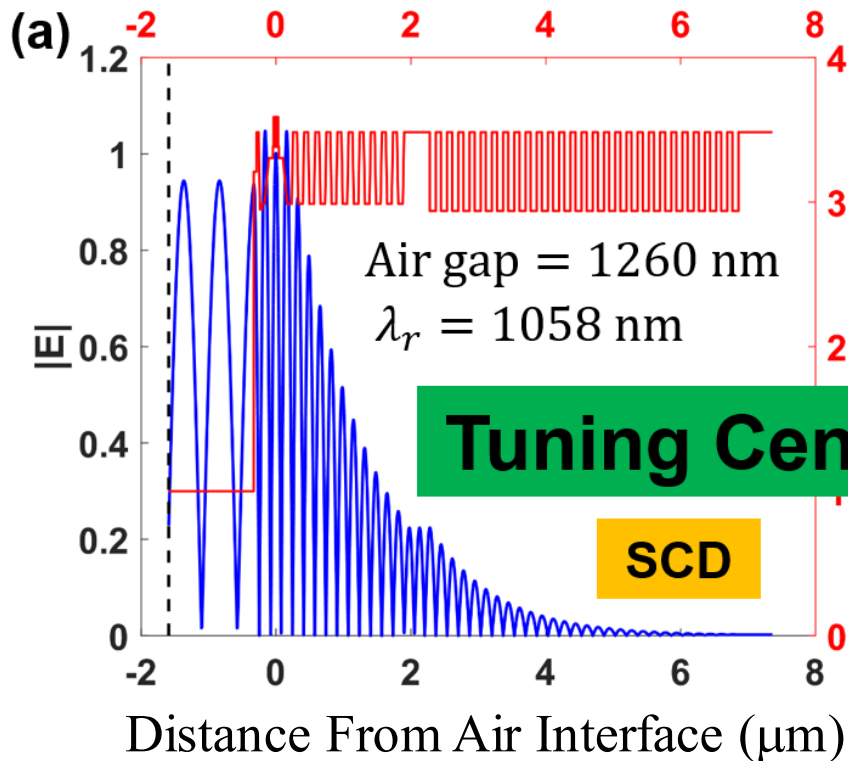
- Static tuning range spans 1023.2 nm to 1096.3 nm
- Fractional tuning range $\Delta\lambda/\lambda = \mathbf{6.9\%}$



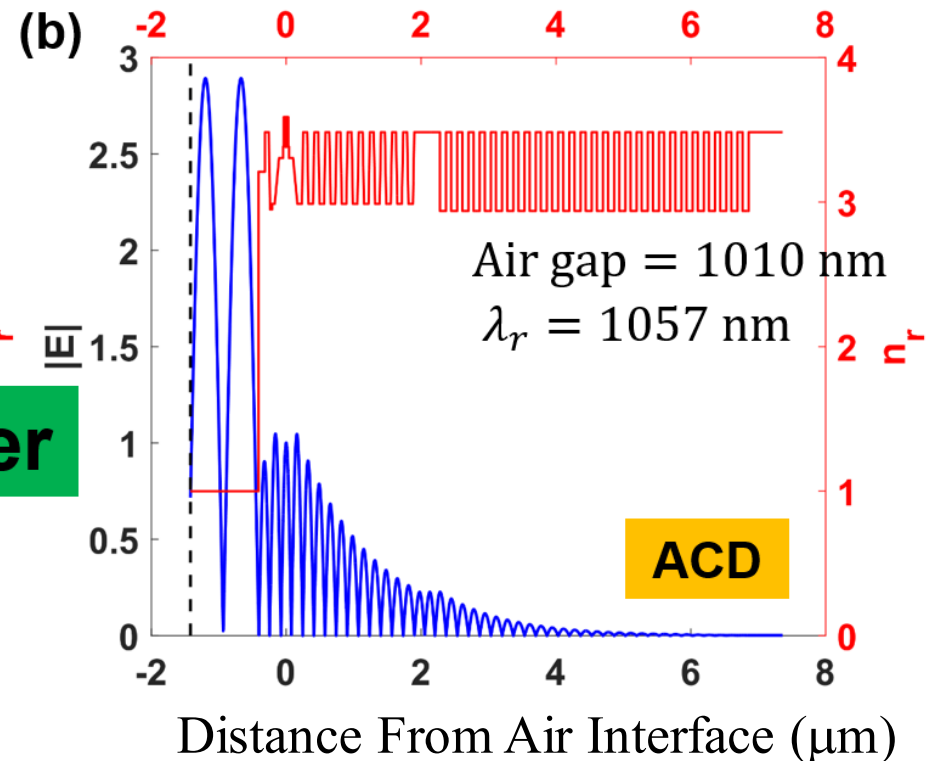
Qiao, Cook, Li, Chang-Hasnain, IEEE JSTQE. **23**, 1700516 (2017).

Conventional Wisdom: *Don't Do it!*

SCD VCSEL with an Airgap



ACD VCSEL with an Airgap



Qiao, Cook, Li, Chang-Hasnain,
IEEE JSTQE. **23**, 1700516 (2017).



Resonant Cavity and Optical Confinement

Conference on Lasers and Electro-Optics, Anaheim, CA



Wednesday

AFTERNOON

27 April 1988

WM

PACIFIC BALLROOM A/B

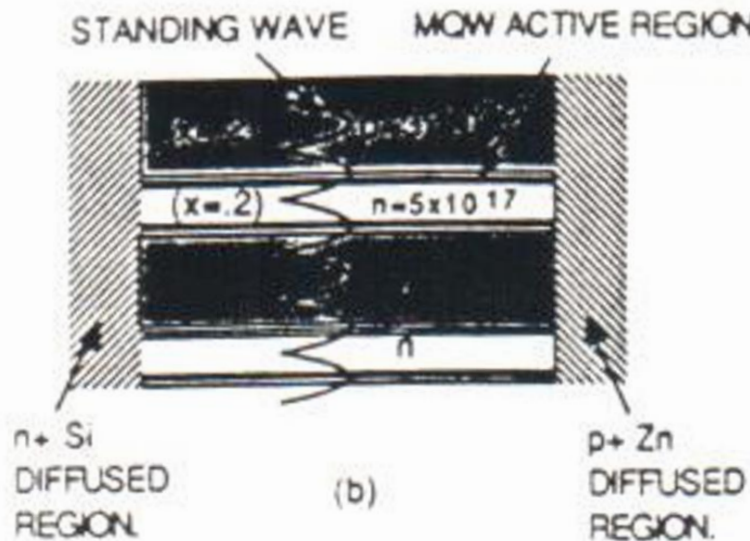
1:00 PM Poster Session: 2

SEMICONDUCTOR DIODE LASERS

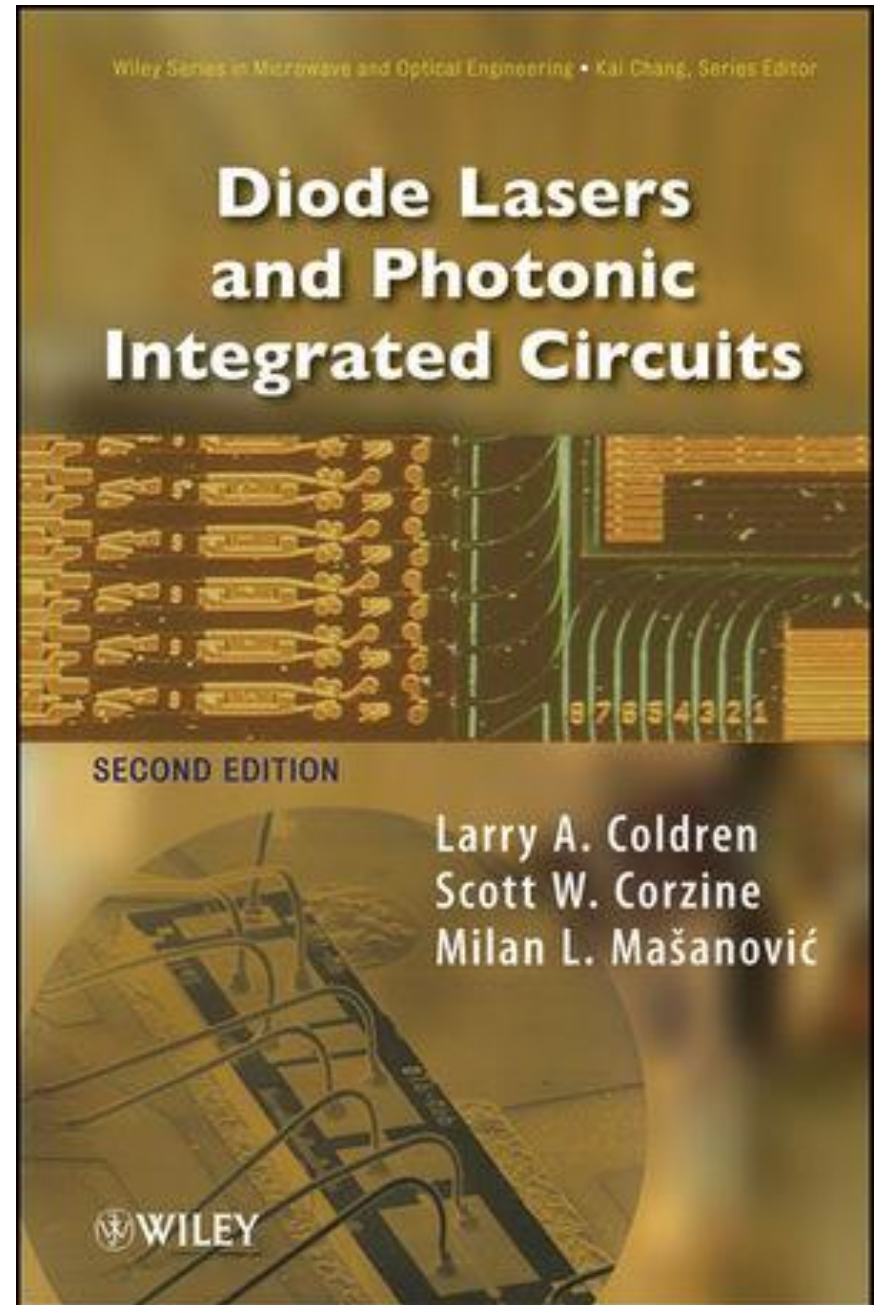
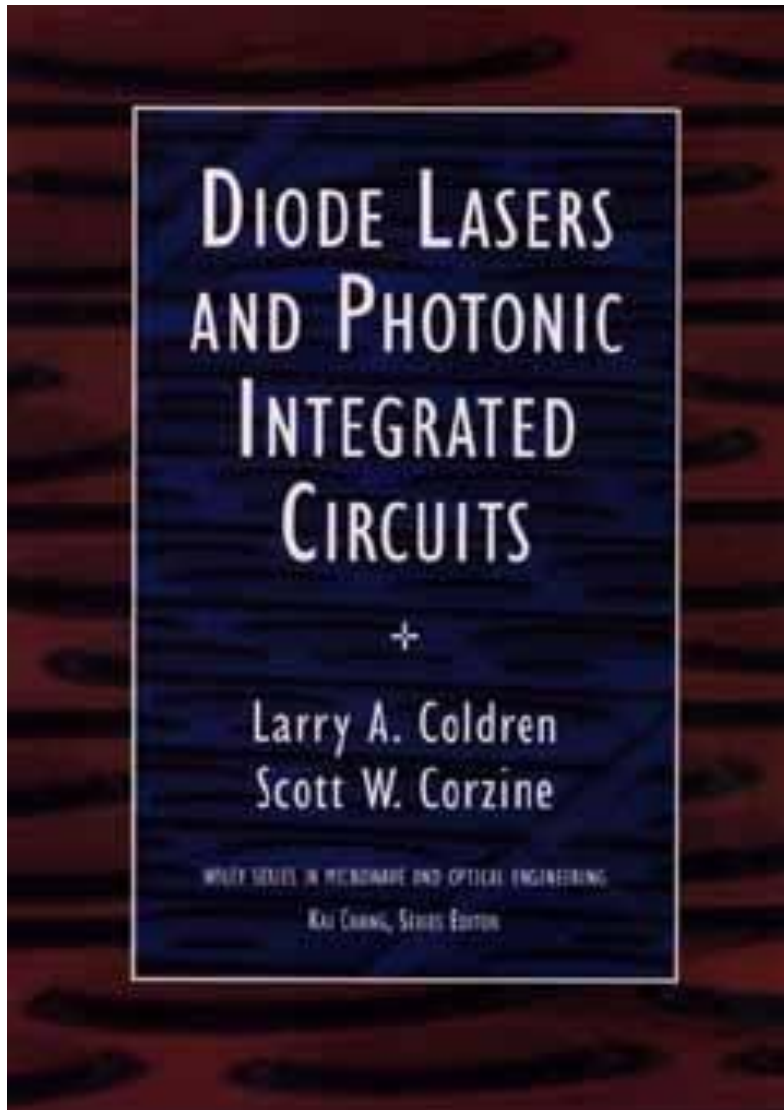
WM1 Analysis and design of a novel parallel-driven MQW-DBR surface-emitting diode laser

R. GEELS, R. H. YAN, J. W. SCOTT, S. W. CORZINE, R. J. SIMES, LARRY A. COLDREN, UC-Santa Barbara, Electrical & Computer Engineering Dept., Santa Barbara, CA 93106.

Several significant features of our design are indicated in Fig. 1(b). The MQW-undoped active regions are placed at maxima of the cavity standing-wave pattern, and the lossy highly doped regions are centered on standing-wave nulls. This, together with the fact that the entire lateral mode width crosses the MQW active regions, results in a much higher net confinement factor (~ 0.2) than in



The BOOK



Wide, Continuously Swept VCSEL Using a Novel Air-Cavity-Dominant Design

Pengfei Qiao¹, Kevin T. Cook¹, Jipeng Qi¹, Larry A. Coldren² and Connie J. Chang-Hasnain¹

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2: Department of Electrical and Computer Engineering, University of California, Santa Barbara, CA 93117, USA

Email address: cch@berkeley.edu

Abstract: We report electrically-pumped MEMS-VCSELs with a record 70 nm continuous wavelength sweep at 1057-nm with 600 kHz rate using a novel air-cavity-dominant design. Such devices are promising for swept-source OCT and 3D sensing applications.

OCIS codes: (140.7260) Vertical cavity surface emitting lasers; (050.6624) Subwavelength structures; (230.4685) Optical microelectromechanical devices; (260.2110) Electromagnetic optics; (140.3600) Lasers, tunable.

OFC 2018

Research Article

optica

Air Cavity Dominant VCSELs with a Wide Wavelength Sweep

KEVIN T. COOK,¹ PENGFEI QIAO,¹ JIPENG QI,¹ LARRY A. COLDREN,² AND CONNIE J. CHANG-HASNAIN^{1,*}

¹Department of Electrical Engineering and Computer Sciences and Tsinghua-Berkeley Shenzhen Institute, University of California at Berkeley, Berkeley, CA 94720, USA

²Departments of Electrical and Computer Engineering and Materials, University of California at Santa Barbara, Santa Barbara, CA 93106, USA

*Corresponding author: cch@berkeley.edu

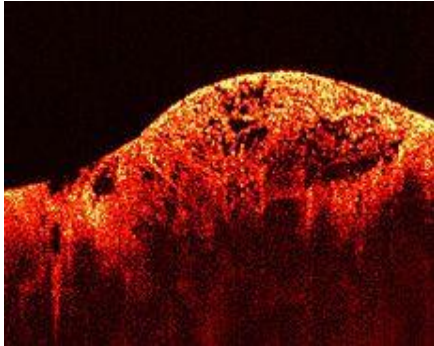


VCSEL30, December 17-18, 2007, Tokyo, Japan



VCSEL35, December 11, 2011, Tokyo, Japan

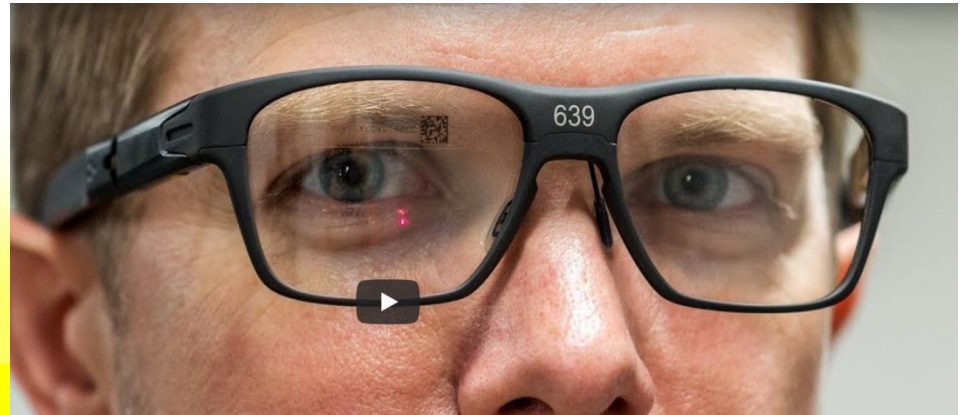




Tomography



Ranging



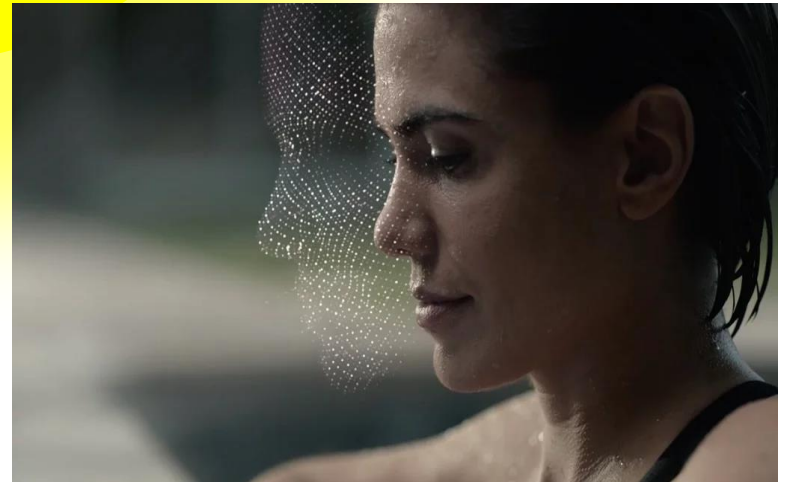
AR & VR

OCT & LIDAR

VCSEL40

3D Sensing

Communications



Congratulations!

